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[Texas Instruments](#)
[CD4010BQDRQ1](#)

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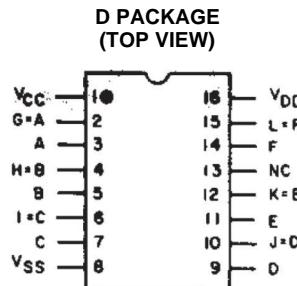
sales@integrated-circuit.com

CMOS HEX BUFFER/CONVERTER

 Check for Samples: [CD4010B-Q1](#)

FEATURES

- Qualified for Automotive Applications
- 100% Tested for Quiescent Current at 20 V
- Maximum Input Current of 1 μ A at 18 V Over Full Package-Temperature Range:
100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V Parametric Ratings
- Latch-Up Performance Meets 100 mA per JESD 78, Class I



APPLICATIONS

- CMOS to DTL/TTL Hex Converter
- CMOS Current "Sink" or "Source" Driver
- CMOS High-to-Low Logic-Level Converter
- Multiplexer: 1-to-6 or 6-to-1

DESCRIPTION

CD4010B hex buffer/converter may be used as CMOS to TTL or DTL logic-level converters or CMOS high-sink-current drivers.

The CD4050B is the preferred hex buffer replacement for the CD4010B in all applications except multiplexers. For applications not requiring high sink current or voltage conversion, the CD4069UB hex inverter is recommended.

The CD4010B is supplied in 16-lead hermetic dual-in-line ceramic (D) packages.

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 125°C	SOIC – D	Reel of 2500	CD4010BQDRQ1

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

 This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

 ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

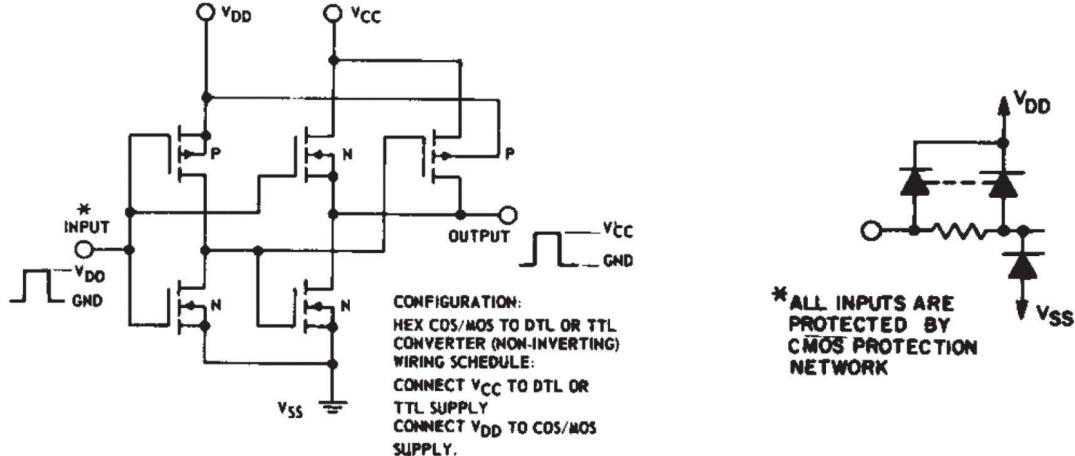
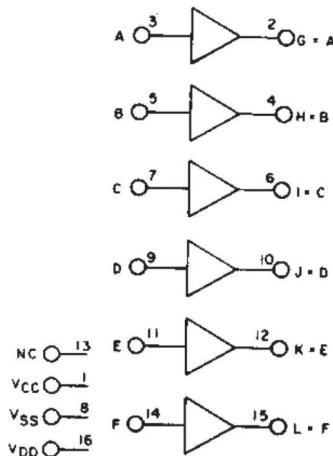


Figure 1. Schematic Diagram – One of Six Identical Stages

Functional Diagram



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		VALUE	UNIT
V_{DD}	DC supply voltage range, voltages referenced to V_{SS} terminal	–0.5 to +20	V
	Input voltage range, all inputs	–0.5 to V_{DD} +0.5	V
	DC input current, any one input	±10	mA
P_D	$T_A = -40^{\circ}\text{C}$ to $+100^{\circ}\text{C}$	500	mW
	$T_A = +100^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	Derate linearly at 12 mW/ $^{\circ}\text{C}$ to 200 mW	
	Device dissipation per output transistor	100	mW
T_A	Operating temperature range	–40 to $+125$	$^{\circ}\text{C}$
T_{stg}	Storage temperature range	–65 to $+150$	$^{\circ}\text{C}$
	Latch-up performance per JESD 78, Class I	100	mA
ESD	Human-body model (HBM)	500	V
	Machine model (MM)	100	
	Charged-Device Model (CDM)	1000	

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Tested in accordance with AEC-Q100.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V_{DD}	Supply voltage range ⁽¹⁾	3	18	V
V_{CC}		3	V_{DD}	
V_I	Input voltage range	V_{CC}	V_{DD}	V

(1) The CD4010B has high-to-low level voltage conversion capability, but not low-to-high level; therefore, it is recommended that $V_{DD} > V_I > V_{CC}$.

STATIC ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)			UNIT		
		V _O	V _{IN}	V _{DD}	-40	+85	+125			
I _{DD} Max	Quiescent device current	0, 5	5	1	30	30	0.02	1	μA	
		0, 10	10	2	60	60	0.02	2		
		0, 15	15	4	120	120	0.02	4		
		0, 20	20	20	600	600	0.04	20		
I _{OL} Min	Output low (sink) current	0.4	0, 5	4.5	3.1	2.1	1.8	2.6	3.4	mA
		0.4	0, 5	5	3.6	2.4	2.1	3	4	
		0.5	0, 10	10	9.6	6.4	5.6	8	10	
		1.5	0, 15	15	40	19	16	24	36	
I _{OH} Min	Output high (source) current	4.6	0, 5	5	-0.23	-0.18	-0.15	-0.2	-0.4	mA
		2.5	0, 5	5	-0.9	-0.65	-0.58	-0.8	-1.6	
		9.5	0, 10	10	-0.5	-0.38	-0.33	-0.45	-0.9	
		13.5	0, 15	15	-1.6	-1.25	-1.1	-1.5	-3	
V _{OL} Max	Output voltage: Low-level	0, 5	5		0.05			0	0.05	V
		0, 10	10		0.05			0	0.05	
		0, 15	15		0.05			0	0.05	
V _{OH} Min	Output voltage: High-level	0, 5	5		4.95			4.95	5	V
		0, 10	10		9.95			9.95	10	
		0, 15	15		14.95			14.95	15	
V _{IL} Max	Input low voltage	0.5		5	1.5				1.5	V
		1		10	3				3	
		1.5		15	4				4	
V _{IH} Min	Input high voltage	4.5		5	3.5			3.5		V
		9		10	7			7		
		13.5		15	11			11		
I _{IN} Max	Input current		0, 18	18	±0.1	±1	±1	±10 ⁻⁵	±0.1	μA

DYNAMIC ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, Input $t_r/t_f = 20$ ns, $C_L = 50$ pf, $R_L = 200$ k Ω

PARAMETER	TEST CONDITIONS					LIMITS ALL PKGS	UNIT
	V_{DD} (V)	V_I (V)	V_{CC} (V)	TYP	MAX		
t_{PLH} Propagation delay time: low-to-high	5	5	5	100	200	ns	ns
	10	10	10	50	100		
	10	10	5	50	100		
	15	15	15	35	70		
	15	15	5	35	70		
t_{PHL} Propagation time: high-to-low	5	5	5	65	130	ns	ns
	10	10	10	35	70		
	10	10	5	30	70		
	15	15	15	25	50		
	15	15	5	20	40		
t_{TLH} Transition time: low-to-high	5	5	5	150	350	ns	ns
	10	10	10	75	150		
	15	15	15	55	110		
t_{THL} Transition time: high-to-low	5	5	5	35	90	ns	ns
	10	10	10	20	45		
	15	15	15	15	40		
C_{IN} Input capacitance				5	7.5	pF	

TYPICAL CHARACTERISTICS

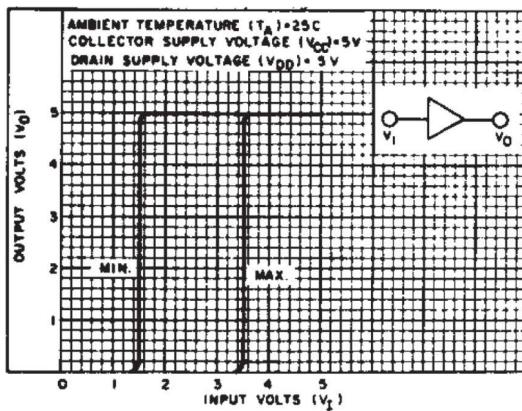


Figure 2. Minimum and Maximum Voltage Transfer Characteristics ($V_{DD} = 5$ V)

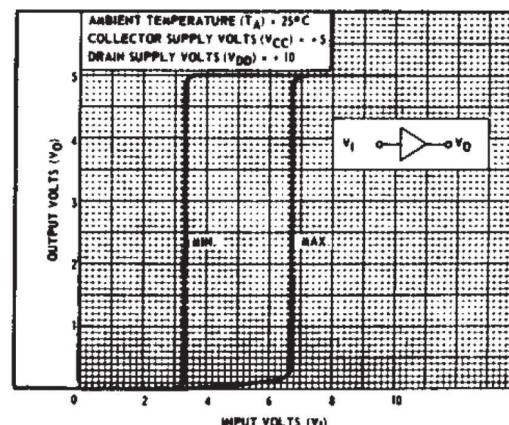


Figure 3. Minimum and Maximum Voltage Transfer Characteristics ($V_{DD} = 10$ V)

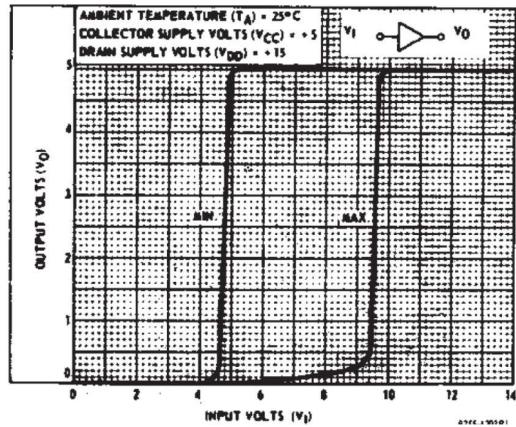


Figure 4. Minimum and Maximum Voltage Transfer Characteristics ($V_{DD} = 15$ V)

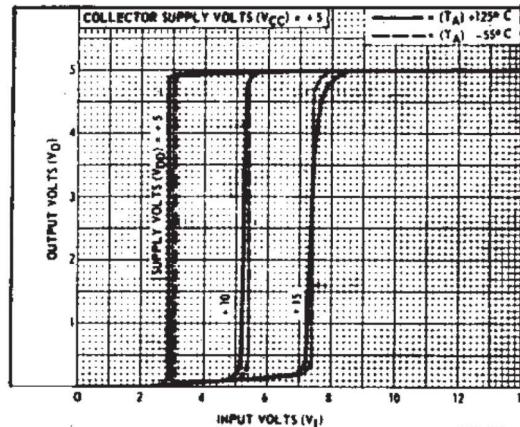


Figure 5. Typical Voltage Transfer Characteristics as a Function of Temperature

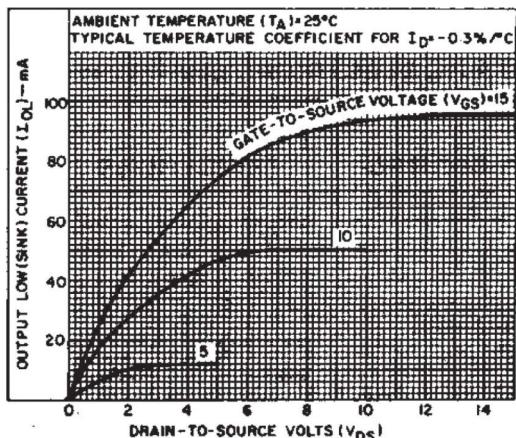


Figure 6. Typical Output Low (Sink) Current Characteristics

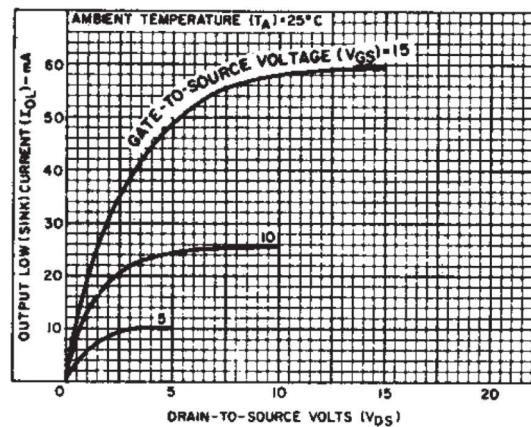


Figure 7. Minimum Output Low (Sink) Current Characteristics

TYPICAL CHARACTERISTICS (continued)

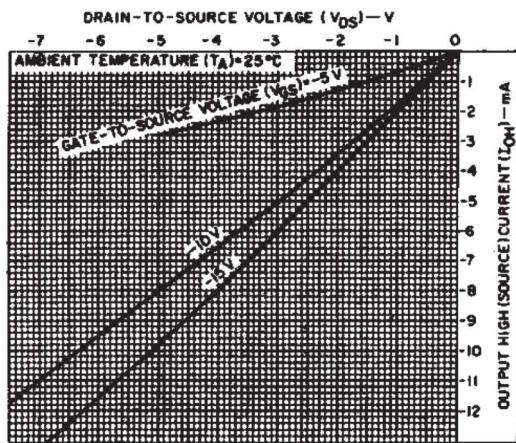


Figure 8. Typical Output High (Source) Current Characteristics

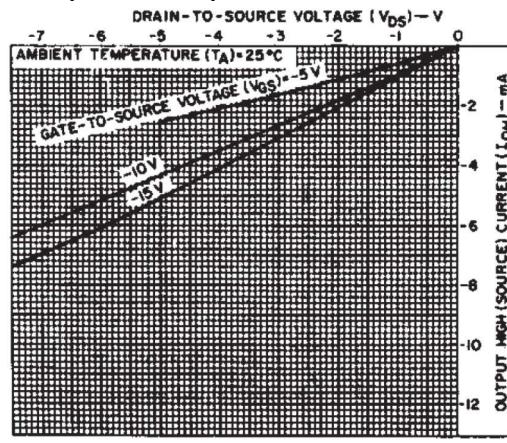


Figure 9. Minimum Output High (Source) Current Characteristics

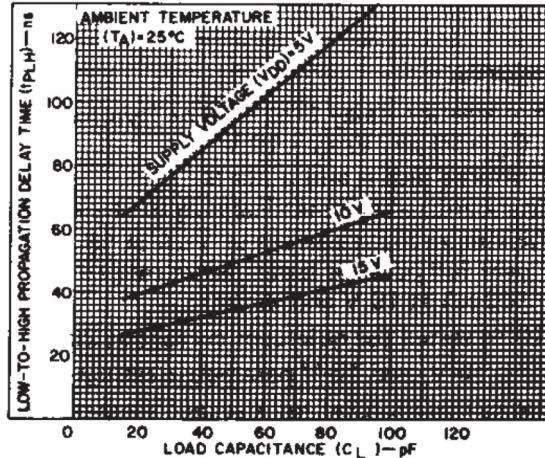


Figure 10. Typical Low-to-High Propagation Delay Time vs Load Capacitance

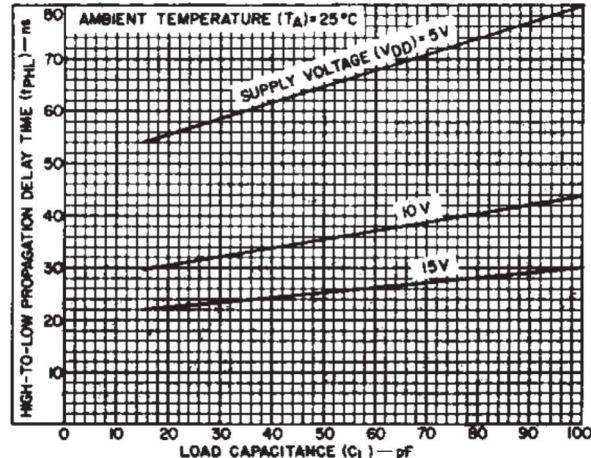


Figure 11. Typical High-to-Low Propagation Delay Time vs Load Capacitance

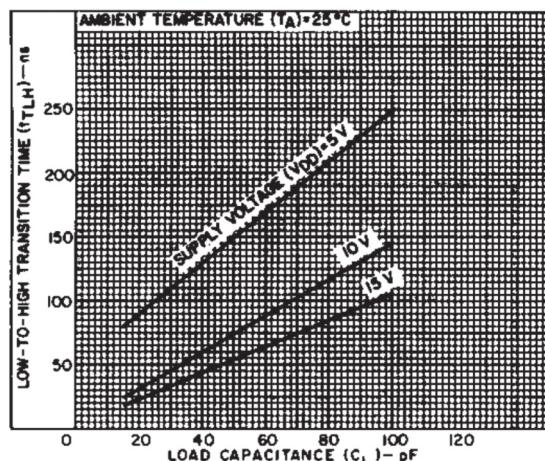


Figure 12. Typical Low-to-High Transition Time vs Load Capacitance

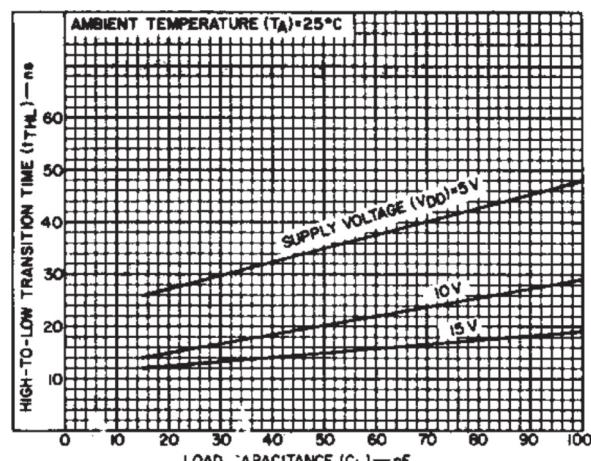


Figure 13. Typical High-to-Low Transition Time vs Load Capacitance

TYPICAL CHARACTERISTICS (continued)

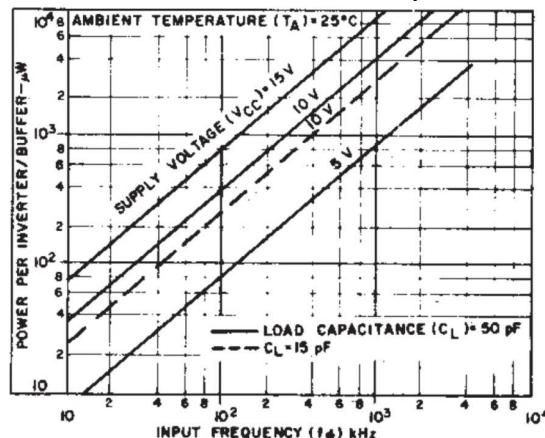


Figure 14. Typical Dissipation Characteristics

PARAMETER MEASUREMENT INFORMATION

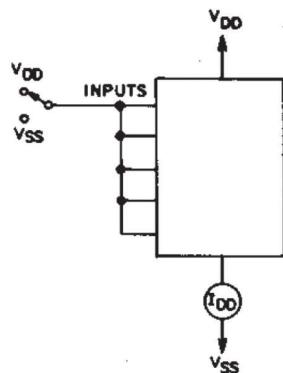


Figure 15. Quiescent Device Current Test Circuit

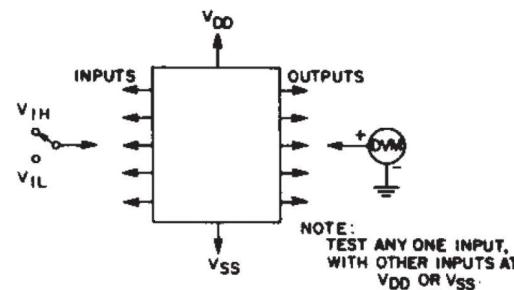


Figure 16. Noise Immunity Test Circuit

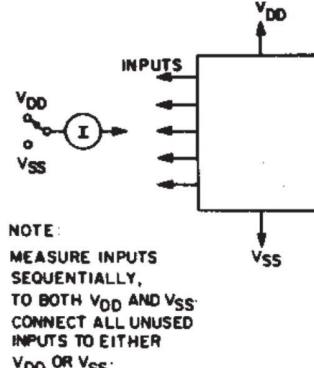
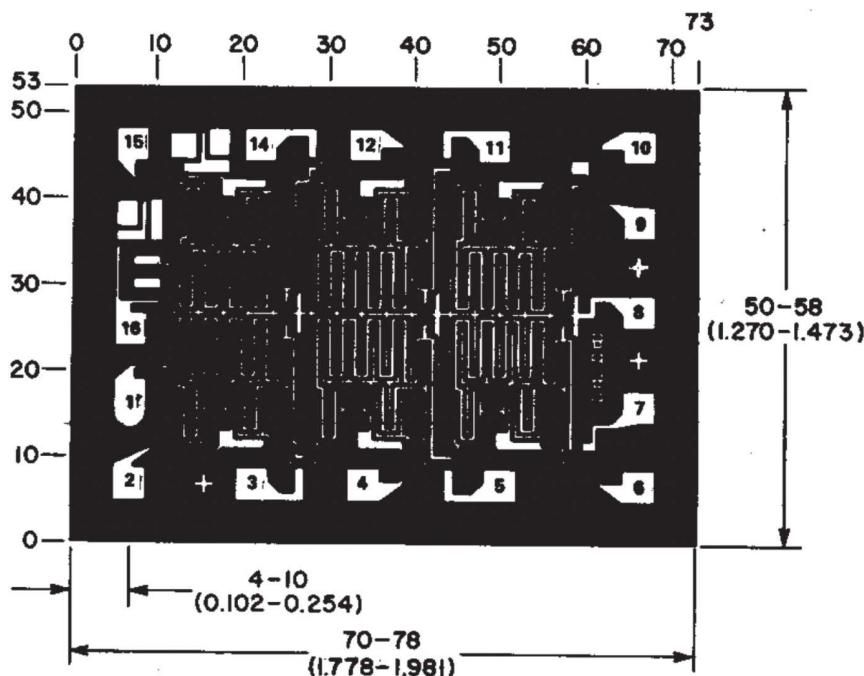


Figure 17. Input Current Test Circuit



Note: Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduation are in mils (10^{-3} inch).

Figure 18. Dimensions and Layout

REVISION HISTORY**Changes from Original (March 2010) to Revision A****Page**

- Changed STATIC ELECTRICAL CHARACTERISTICS table to correct typos and misplaced data 4

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4010BQDRQ1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF CD4010B-Q1 :

- Catalog: [CD4010B](#)
- Military: [CD4010B-MIL](#)

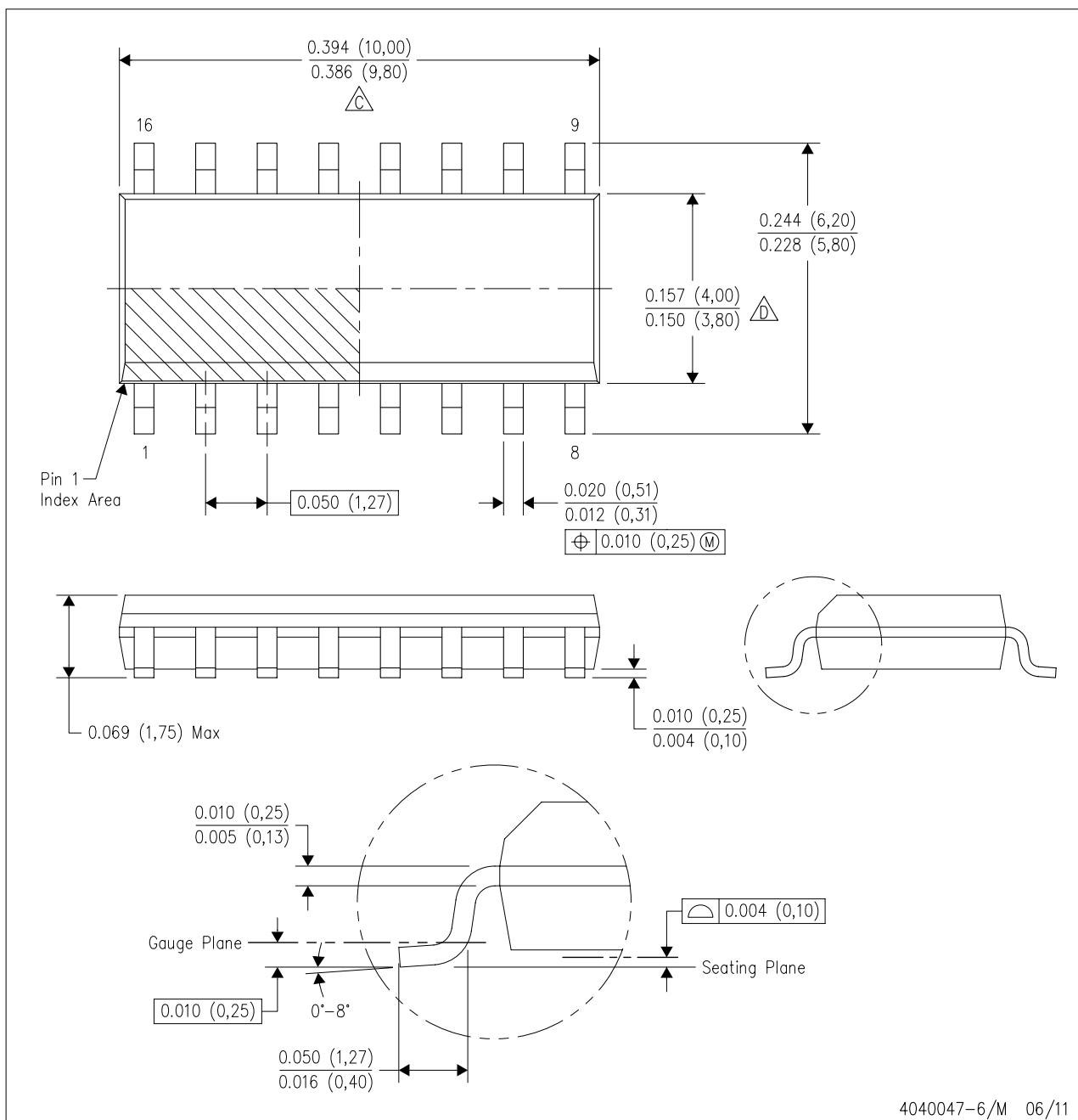
NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

MECHANICAL DATA

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall

 Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0.43) each side.

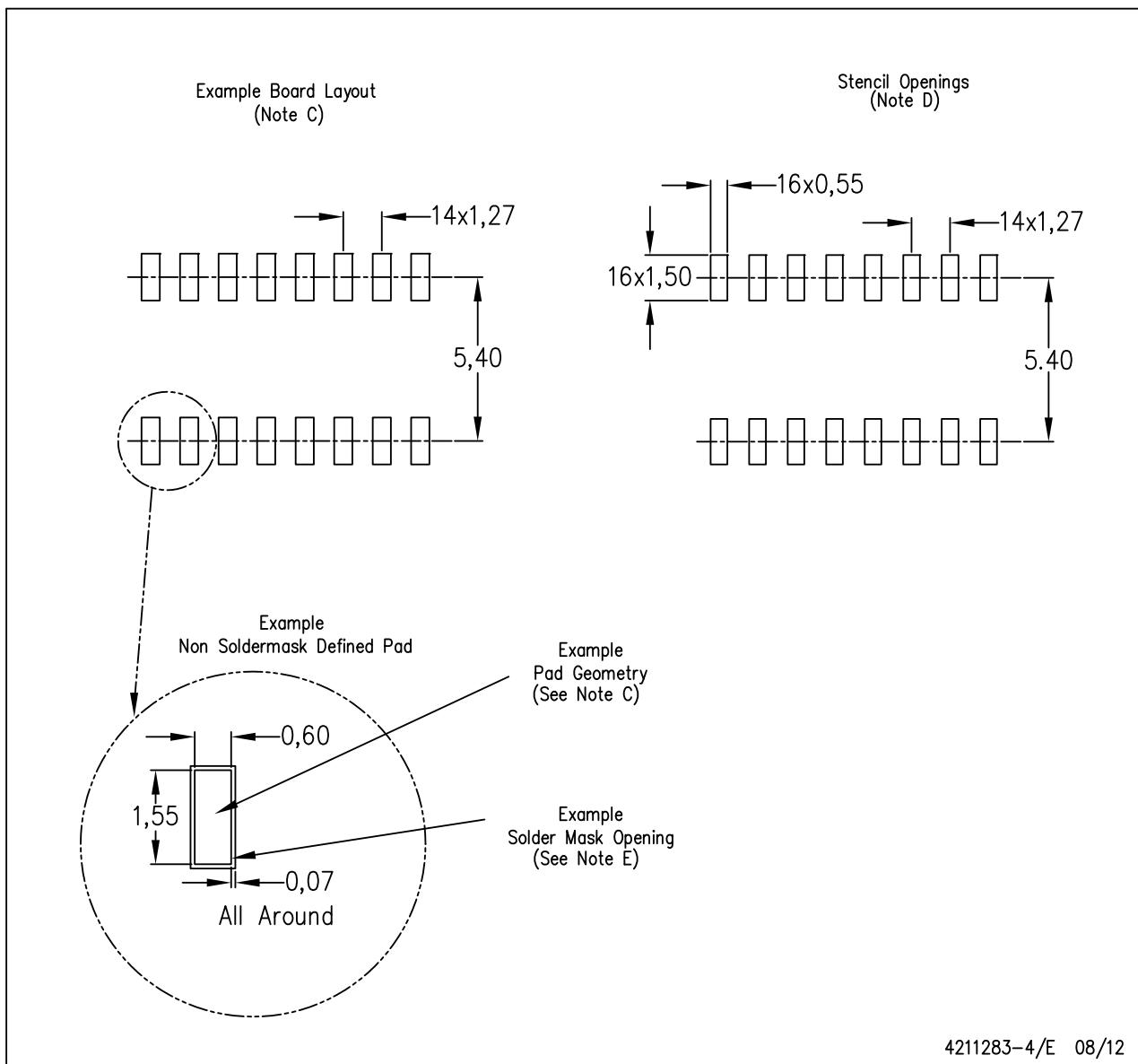
Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0.43) each side.

E. Reference GEDEC MS 012 Variation Ac.

LAND PATTERN DATA

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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